

MBR10...CT MBRB10...CT MBR10...CT-1

Technical Data Data Sheet N0735, Rev. A





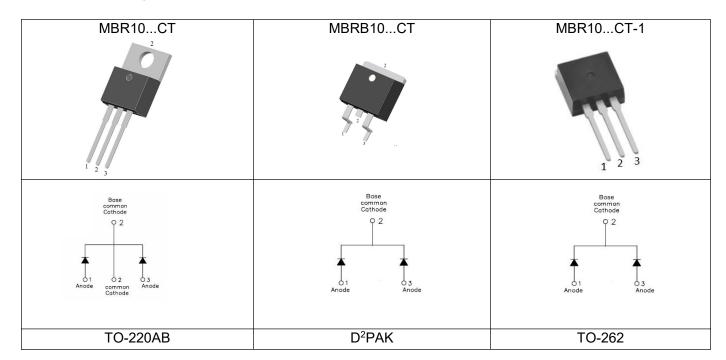
MBR1080/90/100CT MBRB1080/90/100CT MBR1080/90/100CT-1 SCHOTTKY RECTIFIER

Features

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	V_{RRM}	-	80	MBR1080CT	
Working Peak Reverse Voltage	V _{RWM}		90	MBR1090CT	V
DC Blocking Voltage	V _R		100	MBR10100CT	
Average Rectified Forward Current	le (mo	Tc=142°C, In DC 5(Per Leg)		5(Per Leg)	_ A
Average Nectified Forward Current	IF (AV)	I _{F (AV)} I C=142°C, In DC	10(Per Device)		_ ^
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, $T_C = 25 ^{\circ}C$	120		А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 3A, Pulse, T _J = 25 °C @ 5A, Pulse, T _J = 25 °C	0.70 0.79	0.78 0.85	V
	V _{F2}	@ 3 A, Pulse, T _J = 125 °C @ 5 A, Pulse, T _J = 125 °C	0.60 0.65	0.65 0.75	٧
Reverse Current (Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.02	1.00	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	4	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	151	300	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

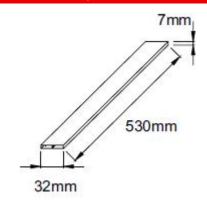
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _θ JC	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	R _{ecs}	Mounting surface, smooth and greased	0.5	°C/W
Case Style	TO-220AB D ² PAK TO-262			

Tube Specification

Device	Package	Weight	Shipping
MBR10CT	TO-220AB	1.8g	50pcs / tube
MBRB10CT	D ² PAK	1.85g	800pcs / reel
MBR10CT-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB/TO-262)



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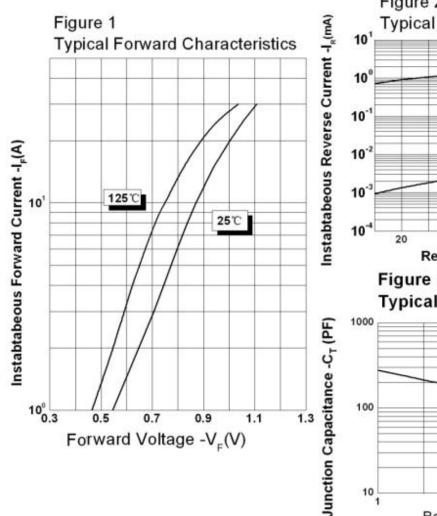


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Ratings and Characteristics Curves



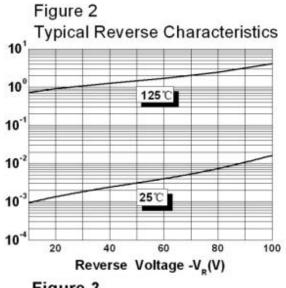
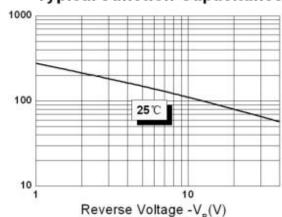


Figure 3
Typical Junction Capacitance



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type
B = Package type
10 = Forward Current (10A)
80/90/100 = Reverse Voltage (80/90/100V)
CT -1 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

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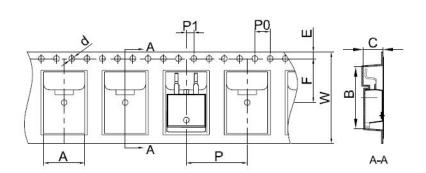


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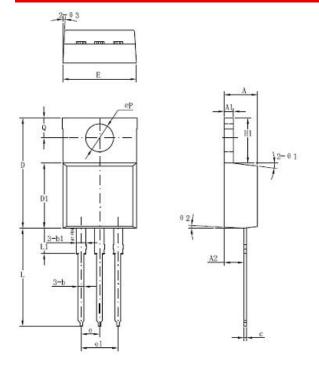


Carrier Tape Specification D²PAK



Symbol	Millimeters		
Symbol	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

Mechanical Dimensions TO-220AB



Symbol	Dimensions in millimeters		
	Min	Typical	Max
А	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

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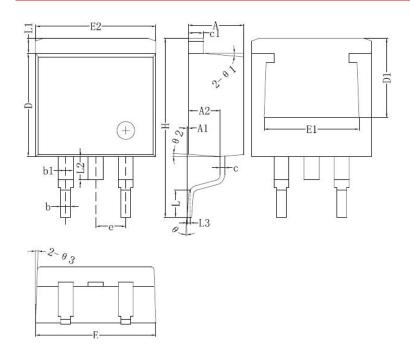


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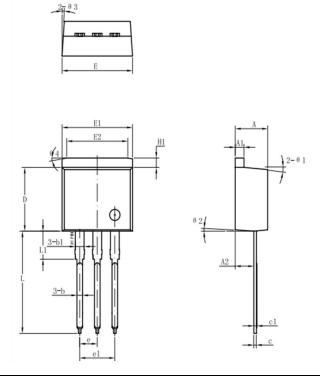


Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.541	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

Mechanical Dimensions TO-262



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
	0	-	8°	
Θ1		5°		
Θ2		4°		
Θ3		4°		
Θ4		10°		

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